NSN 5962-01-373-5203

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Between 1.260 inches and 1.280 inches

Body Width:

Between 0.290 inches and 0.310 inches

Body Height:

Between 0.180 inches and 0.200 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Eo lorops

Features Provided:

Burn in and compatible cmos and electrostatic sensitive and monolithic and programmed and tested to mil-std-883 and ultraviolet erasable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

22 input

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-9 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, programmed

Voltage Rating And Type Per Characteristic:

-5.0 volts power source and 7.0 volts power source

Memory Device Type:

Pal

Special Features:

Electrostatic discharge sensitive; altered item, made from device 5962-8753901lx, programmed per 1061-u56.Jed, fd137200053-001, checksum 962f; nha pn 1372ae1061

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

Fiig:

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